

### DESCRIPTION

The MCS1801 is a linear Hall-effect current sensor for AC or DC current sensing. The Hall array is differential, which cancels out any stray magnetic field.

A primary conductor with a low resistance allows current to flow close to the IC, which contains high-accuracy Hall-effect sensors. This current generates a magnetic field that is sensed at two different points by the integrated Hall-effect transducers. The magnetic field difference between these two points is then converted into a voltage that is proportional to the applied current. A spinning current technique is used for a low and stable offset.

The galvanic isolation between the pins of the primary conductive path and the sensor leads allows the MCS1801 to replace opto-isolators or other isolation devices.

The MCS1801 requires a minimal number of readily available, standard external components. The device's small footprint saves board area and makes it well-suited for space-constrained applications. The MCS1801 is available in an SOIC-8 package.

### FEATURES

- 5V Single Supply
- Immune to External Magnetic Fields by Differential Sensing
- 200V<sub>RMS</sub> Working Voltage for Basic Isolation
- -40°C to +125°C Operating Temperature
- 1.2m $\Omega$  Internal Conductor Resistance
- $\pm 12.5\text{A}$  and  $\pm 25\text{A}$  Range
- Adjustable Bandwidth Up to 100kHz
- 4 $\mu\text{s}$  Output Rising Time
- Ratiometric Output from Supply Voltage
- Output Proportional to AC or DC Currents
- Factory-Trimmed for Accuracy
- No Magnetic Hysteresis
- Available in an SOIC-8 Package



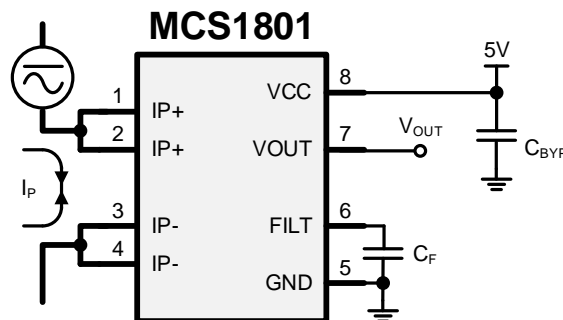
CB Certificate Number:  
CA-11398-UL

### APPLICATIONS

- Motor Controls
- Automotive Systems
- Load Detection and Management
- Switch-Mode Power Supplies
- Over-Current Fault Protection

All MPS parts are lead-free, halogen-free, and adhere to the RoHS directive. For MPS green status, please visit the MPS website under Quality Assurance. "MPS", the MPS logo, and "Simple, Easy Solutions" are trademarks of Monolithic Power Systems, Inc. or its subsidiaries.

### TYPICAL APPLICATION



#### Note:

- 1)  $V_{OUT}$  is proportional to  $I_p$  within the specified range. The noise vs. bandwidth tradeoff can be adjusted by connecting a capacitor ( $C_F$ ) between FILT and GND.

### ORDERING INFORMATION

Part Number*	Optimized Primary Current Range(A)	Typ. Sensitivity (SENS)(mV/A)	Top Marking	MSL Rating
MCS1801GS-12	±12.5	160	MC180112	1
MCS1801GS-25	±25	80	MC180125	

\* For Tape & Reel, add suffix -Z (e.g. MCS1801GS-12-Z).

### TOP MARKING (MCS1801GS-12)

MC180112  
 LLLLLLLL  
 MPSYWW

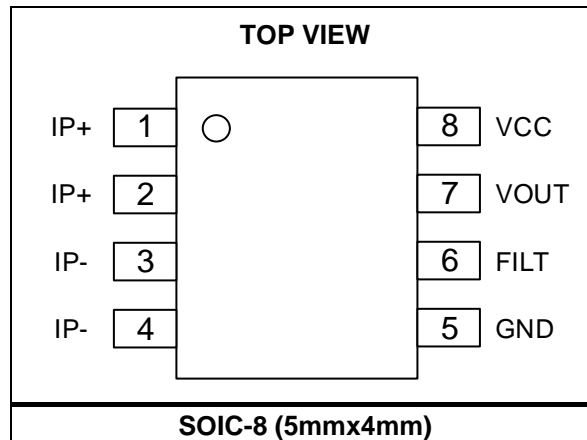
MC180112: Part number  
 LLLLLLLL: Lot number  
 MPS: MPS prefix  
 Y: Year code  
 WW: Week code

### TOP MARKING (MCS1801GS-25)

MC180125  
 LLLLLLLL  
 MPSYWW

MC180125: Part number  
 LLLLLLLL: Lot number  
 MPS: MPS prefix  
 Y: Year code  
 WW: Week code

### PACKAGE REFERENCE



## PIN FUNCTIONS

Pin #	Name	Description
1, 2	IP+	<b>Primary current (+).</b> IP+ is a terminal for the current being sampled. These pins are internally connected together.
3, 4	IP-	<b>Primary current (-).</b> IP- is a terminal for the current being sampled. These pins are internally connected together.
5	GND	<b>Ground.</b> Signal ground terminal.
6	FILT	<b>Filter.</b> FILT is a terminal for the external capacitor ( $C_F$ ), which sets the bandwidth. FILT can be left floating when the bandwidth setting is not required.
7	VOUT	<b>Analog output.</b>
8	VCC	<b>Voltage supply.</b> Connect VCC to a 5V power supply. Bypass with a 1 $\mu$ F low ESR ceramic capacitor as close to VCC pin as possible.

### ABSOLUTE MAXIMUM RATINGS <sup>2)</sup>

Supply Voltage ( $V_{CC}$ ).....-0.1V to +6V  
 Output Voltage ( $V_{OUT}$ ) .....-0.1V to +6V  
 $V_{FILT}$ .....-0.1V to +6V  
 Junction temperature ..... 165°C  
 Lead temperature .....260°C  
 Storage temperature ..... -65°C to +165°C

### ESD Ratings

Human body model (HBM) ..... ±2kV  
 Charged device model (CDM) ..... ±2kV

### Recommended Operating Conditions <sup>3)</sup>

Supply voltage ( $V_{CC}$ ) ..... 4.5V to 5.5V  
 Operating junction temp ( $T_J$ ).....-40°C to +125°C

#### Notes:

- 2) Exceeding these ratings may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.

## ISOLATION CHARACTERISTICS

Parameters	Symbol	Condition	Rating	Units
Withstand isolation voltage	$V_{ISO}$	Agency type-tested for 60 seconds in accordance with IEC62368-1. 100% Tested in production in accordance with IEC 62368-1.	1000	$V_{RMS}$
Maximum isolation working voltage	$V_{IOWM}$	Maximum approved isolation working voltage for basic isolation, according to IEC62368-1.	280	$V_{PK}$ or $V_{DC}$
			200	$V_{RMS}$
External clearance	CLR	Shortest distance through the air from the IP leads to the signal leads.	4.2	mm
External creepage	CPG	Shortest distance along the package body from the IP leads to the signal leads.	4.2	mm

## WITHSTANDING CURRENT CAPABILITY

Parameters	Symbol	Condition	Rating	Units
Transient current test <sup>(4)</sup>	$I_{TRANSIENT}$	Single peak, 10ms	250	A

**Note:**

4) For the detailed transient current capability test, refer to MPS application note AN178.

## MCS1801 COMMON ELECTRICAL CHARACTERISTICS

$V_{CC} = 5V$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , unless otherwise noted. Typical values at  $T_J = 25^{\circ}C$ .

Parameters	Symbol	Condition	Min	Typ Error! Reference source not found.	Max	Units
Supply voltage	$V_{CC}$		4.5		5.5	V
VCC under-voltage lockout threshold	$V_{CC\_UVLO}$	$V_{CC}$ rising	2	2.5	3	V
VCC under-voltage lockout hysteresis	$V_{CC\_UVLO\_HYS}$			400	750	mV
Operating supply current	$I_{CC}$	$V_{CC} = 5V$		8.5	10.5	mA
Output capacitance load <sup>(9)</sup>	$C_L$	From $V_{OUT}$ to GND			10	nF
Output resistive load <sup>(9)</sup>	$R_L$	From $V_{OUT}$ to GND	4.7			k $\Omega$
Primary conductor resistance <sup>(10)</sup>	$R_P$	Effective		1.2		m $\Omega$
Frequency bandwidth	$f_{BW}$	FILT disconnected		100		kHz
Internal filter resistance	$R_{Fi}$			1.5		k $\Omega$
Internal filter capacitance	$C_{Fi}$			1		nF
Power-on time	$t_{PO}$	$I_P = I_{P_{MAX}}$ , FILT disconnected		90		$\mu$ s
Rise time	$t_R$	$I_P = I_{P_{MAX}}$ , FILT disconnected		4		$\mu$ s
Propagation delay	$t_{PD}$	$I_P = I_{P_{MAX}}$ , FILT disconnected		1.5		$\mu$ s
Response time	$t_{RESPONSE}$	$I_P = I_{P_{MAX}}$ , FILT disconnected		5		$\mu$ s
Noise density	$I_{ND}$	Input referred noise density		200		$\mu A_{(RMS)}/\sqrt{Hz}$
Noise	$I_N$	Input referred, 1nF on FILT (60kHz bandwidth)		50		$mA_{(RMS)}$
Nonlinearity	$E_{LIN}$	Across the full $I_P$ range		0.5		%
Ratiometry	$K_{SENS}$	$V_{CC} = 4.5$ to $5.5V$	97.5	100	102.5	%
	$K_{V0}$	$V_{CC} = 4.5$ to $5.5V$ , $I_P = 0A$	99	100	101	%
Zero current output voltage	$V_{OUT(Q)}$	$I_P = 0A$		$V_{CC} / 2$		V
First Hall magnetic coupling factor	$P_{MCF1}$			0.6		mT/A
Second Hall magnetic coupling factor	$P_{MCF2}$			0.3		mT/A
Hall plate matching	$M_H$			$\pm 1$		%
Saturation voltage <sup>(6) (9)</sup>	$V_{OUT(H)}$	$R_L = 4.7k\Omega$ , $T_J = 25^{\circ}C$	$V_{CC} - 0.5$			V
	$V_{OUT(L)}$	$R_L = 4.7k\Omega$ , $T_J = 25^{\circ}C$			0.5	V

## MCS1801-12 PERFORMANCE CHARACTERISTICS

$V_{CC} = 5V$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ <sup>(5)</sup>	Max	Units
Optimized accuracy range <sup>(7)</sup>	$I_P$		-12.5		+12.5	A
Sensitivity	SENS	$-12.5A \leq I_P \leq +12.5A$ , $T_J = 25^{\circ}C$		160		mV/A
Sensitivity error	$E_{SENS}$	$I_P = 12.5A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-2.5		+2.5	%
		$I_P = 12.5A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±2		%
Offset voltage <sup>(8)</sup>	$V_{OE}$	$I_P = 0A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-15		+15	mV
		$I_P = 0A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±10		mV
Total output error	$E_{TOT}$	$I_P = 12.5A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-3		+3	%
		$I_P = 12.5A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±2.5		%
Sensitivity error lifetime drift	$E_{SENS(D)}$			±1		%
Total output error lifetime drift	$E_{TOT(D)}$			±1		%

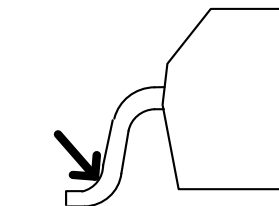
## MCS1801-25 PERFORMANCE CHARACTERISTICS

$V_{CC} = 5V$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ <sup>(5)</sup>	Max	Units
Optimized accuracy range <sup>(7)</sup>	$I_P$		-25		+25	A
Sensitivity	SENS	$-25A \leq I_P \leq +25A$ , $T_J = 25^{\circ}C$		80		mV/A
Sensitivity error	$E_{SENS}$	$I_P = 25A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-2.5		+2.5	%
		$I_P = 25A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±2		%
Offset voltage <sup>(8)</sup>	$V_{OE}$	$I_P = 0A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-15		+15	mV
		$I_P = 0A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±10		mV
Total output error	$E_{TOT}$	$I_P = 25A$ , $T_J = 25^{\circ}C$ to $125^{\circ}C$	-3		+3	%
		$I_P = 25A$ , $T_J = -40^{\circ}C$ to $+25^{\circ}C$		±2.5		%
Sensitivity error lifetime drift	$E_{SENS(D)}$			±1		%
Total output error lifetime drift	$E_{TOT(D)}$			±1		%

### Notes:

- Typical values denoted with the “±” sign signify ±3 sigma values.
- Beyond the maximum specified current range ( $I_P$ ), the current sensor continues to provide an analog output voltage proportional to the primary current until the device reaches the high or low saturation voltage. However, the nonlinearity increases beyond the specified range ( $I_P$ ).
- The device can operate at higher primary current levels ( $I_P$ ) and ambient temperatures ( $T_A$ ), as long as the maximum junction temperature ( $T_J$  (MAX)) is not exceeded.
- The offset voltage does not incorporate any error due to the external magnetic fields.
- Guaranteed by design and characterization.
- The resistance is defined as the total resistance measured from a point of the lead next to the solder joint, assuming that the two  $I_P+$  pins (and  $I_P-$  pins) have the same potential (see Figure 1). This definition corresponds to the effect resistance used to estimate the joule heating, calculated with  $R \times I_P^2$ .

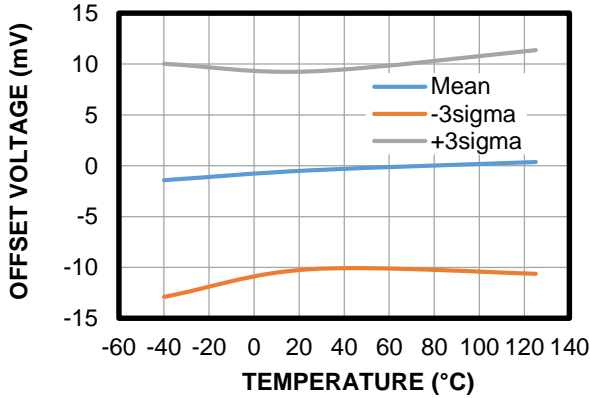


**Figure 1: Total Resistance**

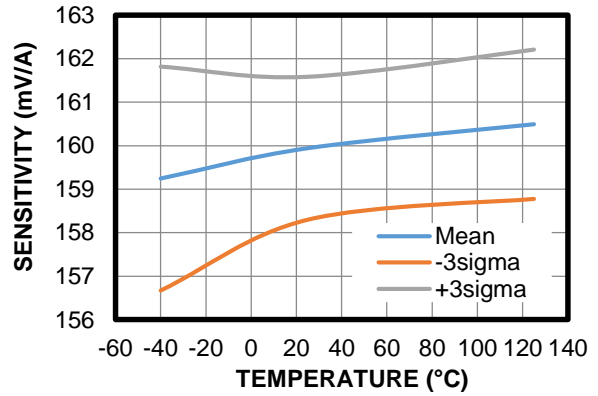
## TYPICAL CHARACTERISTICS

MCS1801GS-12, unless otherwise noted.

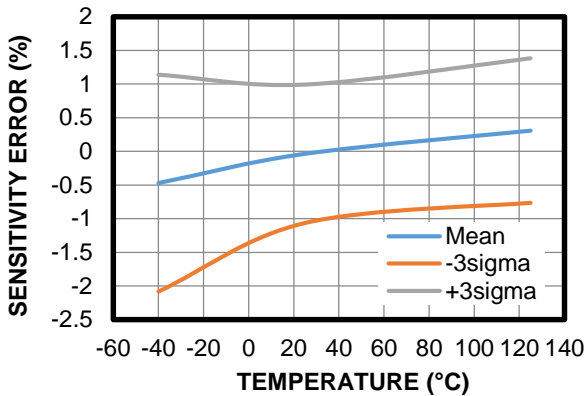
Offset Voltage vs. Temperature



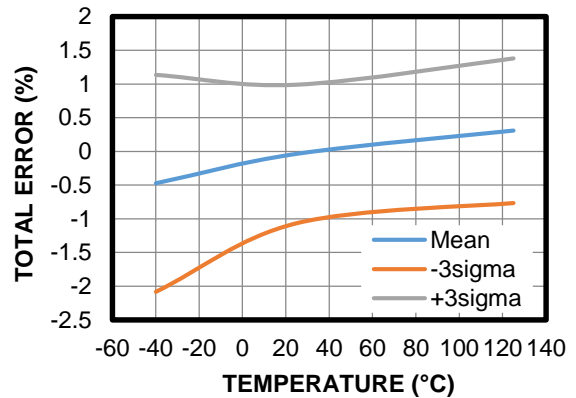
Sensitivity vs. Temperature



Sensitivity Error vs. Temperature



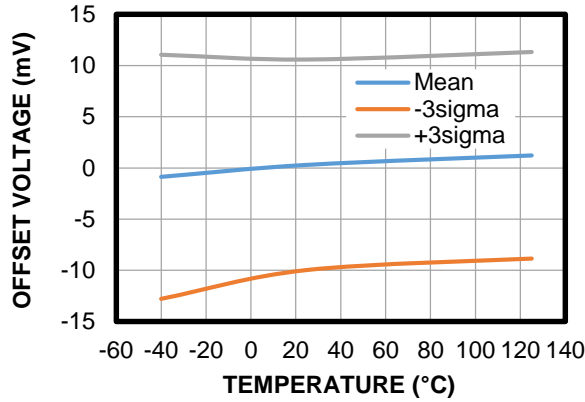
Total Error vs. Temperature



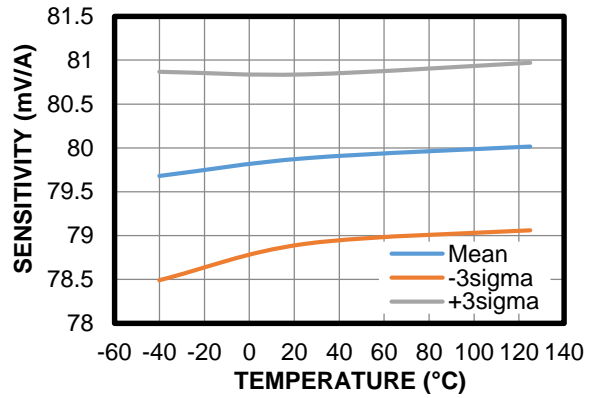
## TYPICAL CHARACTERISTICS

MCS1801GS-25, unless otherwise noted.

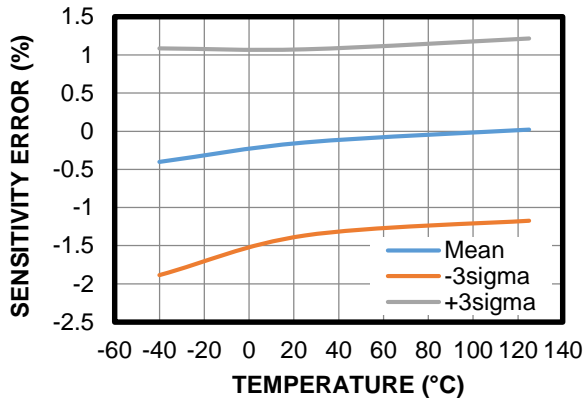
Offset Voltage vs. Temperature



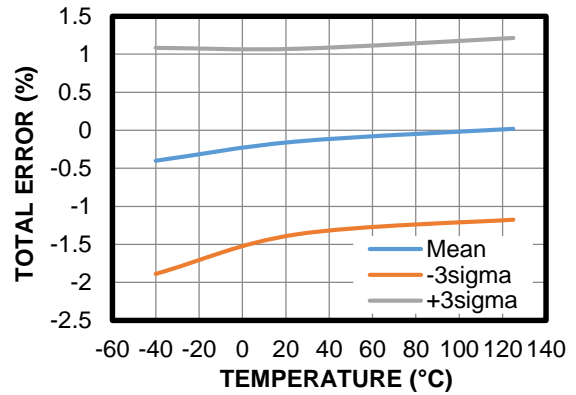
Sensitivity vs. Temperature



Sensitivity Error vs. Temperature



Total Error vs. Temperature





## FUNCTIONAL BLOCK DIAGRAM

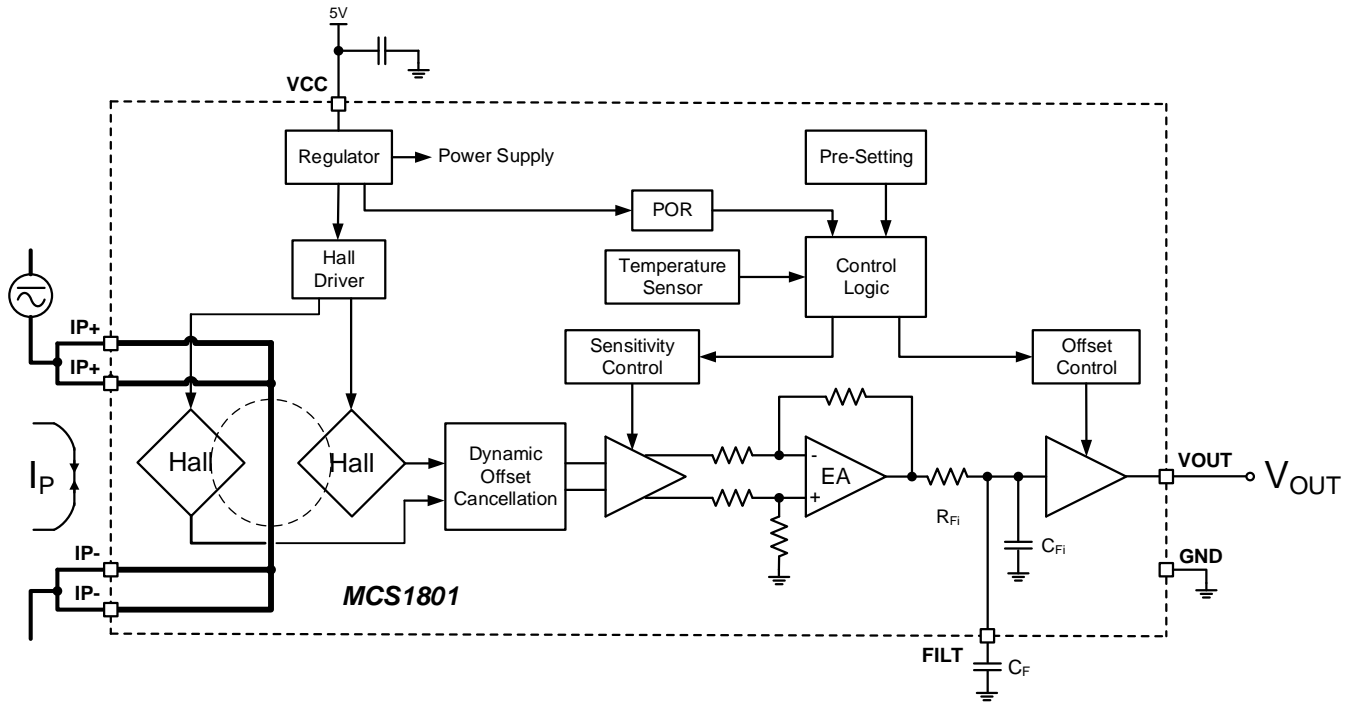
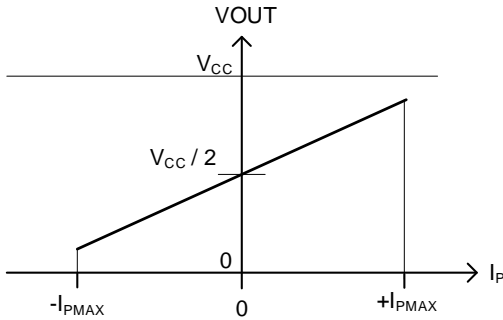


Figure 2: Functional Block Diagram

## OPERATION

### Current Rating

$I_{P_{MAX}}$  is the rated current. The sensor output is linear, as a function of the primary current ( $I_P$ ).  $I_P$  follows the specified performances when  $I_P$  is between  $-I_{P_{MAX}}$  and  $+I_{P_{MAX}}$  (see Figure 3).



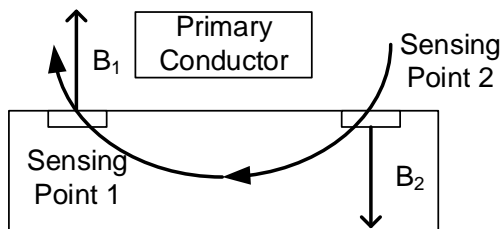
**Figure 3: Sensor Output Function**

### Sensitivity (SENS)

The sensitivity (SENS) (in mV/A) indicates how the output changes when the primary current changes. SENS is the product of the average between the two coupling constants ( $P_{MCF1}$  and  $P_{MCF2}$ ) (in mT/A) and the transducer gain (in mV/mT). The gain is factory-trimmed to the sensor target sensitivity.

### Coupling Constants ( $P_{MCF1}$ and $P_{MCF2}$ )

Figure 4 shows a cross-section of the sensor. The first and second Hall magnetic coupling factors are defined as the amount of the vertical magnetic field ( $B_1$  and  $B_2$ ) produced at the sensing points 1 and 2, per unit of current injected in the primary conductor. Due to the asymmetrical shape of the primary conductor, the magnetic field generated at the two sensing points are different.



**Figure 4: Cross Section of the Sensor**

### Noise ( $I_N$ )

The noise ( $I_N$ ) is a random deviation that cannot be removed by calibrating the device. The input's referred noise is the root mean square of the sensor's output noise (in mV), divided by the

sensitivity (in mV/A).  $I_N$  represents the smallest current that the device is able to resolve without any external signal treatment.

### Zero Current Output Voltage ( $V_{OUT(Q)}$ )

$V_{OUT(Q)}$  is the voltage output when the primary current is 0A. The nominal value is  $V_{CC}/2$ .

### Offset Voltage ( $V_{OE}$ )

The offset voltage ( $V_{OE}$ ) is the difference between  $V_{CC}/2$  and the zero current output voltage  $V_{OUT(Q)}$ . The variation is due to thermal drift, as well as the factory's resolution limits related to voltage offset trimming. To convert this voltage into amperes, divide  $V_{OE}$  by the sensitivity.

### Nonlinearity ( $E_{LIN}$ )

The primary current and sensor output should have a linear relationship, indicated by a straight line. A line that is not straight indicates nonlinearity, which is a deviation.

Nonlinearity (in %) can be calculated with Equation (1):

$$E_{LIN} = \frac{\max(V_{OUT}(I_P) - V_{LIN}(I_P))}{V_{OUT}(I_{P_{MAX}}) - V_{OUT}(-I_{P_{MAX}})} \times 100 \quad (1)$$

Where  $V_{LIN}(I_P)$  is the approximate straight line calculated by the least square method. Note that depending on the curvature of  $V_{OUT}(I_P)$ ,  $E_{LIN}$  can be positive or negative.

### Total Output Error ( $E_{TOT}$ )

$E_{TOT}$  (in %) is the relative difference between the sensor output and the ideal output at a given primary current ( $I_P$ ).  $E_{TOT}$  can be estimated with Equation (2):

$$E_{TOT}(I_P) = \frac{V_{OUT}(I_P) - V_{OUT\_IDEAL}(I_P)}{SENS \times I_P} \times 100 \quad (2)$$

Where  $V_{OUT\_IDEAL}$  can be calculated with Equation (3):

$$V_{OUT\_IDEAL}(I_P) = \frac{V_{CC}}{2} + SENS \times I_P \quad (3)$$

The total output error incorporates all error sources, and is a function of  $I_P$ . At currents close to  $I_{P_{MAX}}$ ,  $E_{TOT}$  is affected mainly by the sensitivity error. At currents close to 0A,  $E_{TOT}$  is mostly caused by the offset voltage ( $V_{OE}$ ). Note that

when  $I_P = 0A$ ,  $E_{TOT}$  diverges to infinity due to the constant offset.

**Ratiometry Coefficients**

Ideally, the sensor output is ratiometric. This means that the sensitivity and the zero current output scale with  $V_{CC}$ . The ratiometry coefficients measure if the sensitivity and zero output current are proportional.

$K_{SENS}$  can be calculated with Equation (4):

$$K_{SENS} = \frac{SENS(V_{CC}) / SENS(3.3V)}{V_{CC} / 3.3V} \quad (4)$$

$K_{VO}$  can be calculated with Equation (5):

$$K_{VO} = \frac{V_{OUT}(I_P = 0, V_{CC}) / V_{OUT}(I_P = 0, 3.3V)}{V_{CC} / 3.3V} \quad (5)$$

Ideally both  $K_{SENS}$  and  $K_{VO}$  are 1.

**Power On Time ( $t_{PO}$ )**

The power on time ( $t_{PO}$ ) is the time interval after power is first applied to the device, until the output can correctly indicate the applied primary current.  $t_{PO}$  is defined as the time between the following moments:

1.  $t_1$ : The supply reaches the minimum operating voltage ( $V_{CC\_UVLO}$ ).
2.  $t_2$ :  $V_{OUT}$  settles 90% of its final value under an applied primary current (see Figure 5).

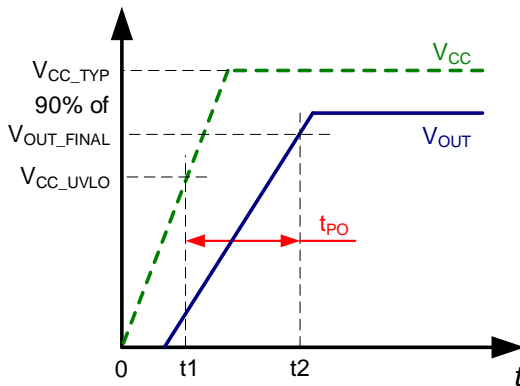


Figure 5: Power-On Time ( $t_{PO}$ )

**Propagation Delay ( $t_{PD}$ )**

The propagation delay ( $t_{PD}$ ) represents the internal latency between an event that has been measured and the sensor's response.  $t_{PD}$  is defined as the time between the following moments:

1.  $t_1$ : The primary current signal reaches 20% of its final value.

2.  $t_2$ :  $V_{OUT}$  reaches 20% of its final value, as it corresponds to the applied primary current (see Figure 6).

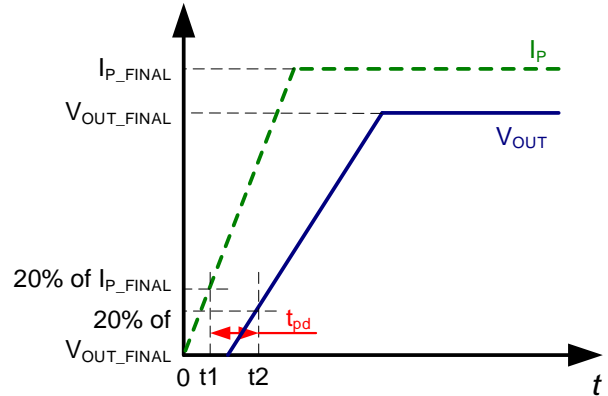


Figure 6: Propagation Delay ( $t_{PD}$ )

**Rising Time ( $t_R$ )**

The rising time ( $t_R$ ) is defined as the time between the following moments:

1.  $t_1$ : The sensor's  $V_{OUT}$  reaches 10% of its full-scale value.
2.  $t_2$ : The sensor's  $V_{OUT}$  reaches 90% of its full-scale value (see Figure 7).

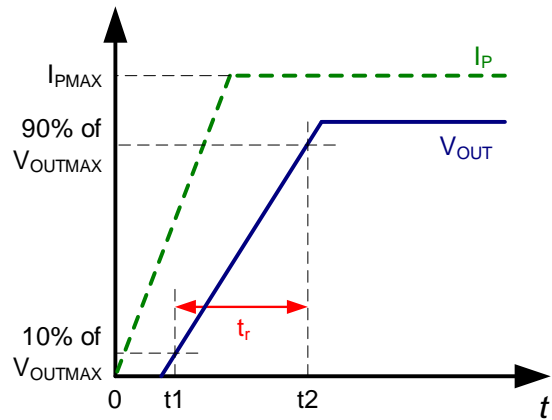


Figure 7: Rise Time ( $t_R$ )

The sensor bandwidth ( $f_{BW}$ ) is defined as the 3dB cutoff frequency. By using the rising time,  $f_{BW}$  can be estimated with Equation (6):

$$f_{BW} = 0.35 / t_R \quad (6)$$

**Response Time ( $t_{RESPONSE}$ )**

The response time ( $t_{RESPONSE}$ ) is defined as the time between the following moments:

1.  $t_1$ : The primary current signal reaches 90% of its final value.
2.  $t_2$ :  $V_{OUT}$  reaches 90% of its final value, as it

corresponds to the applied primary current (see Figure 8).

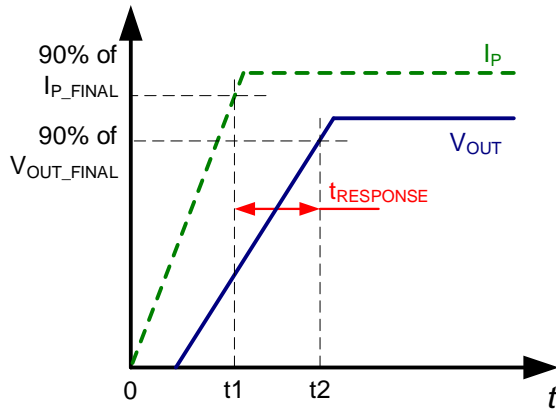


Figure 8: Response Time ( $t_{\text{RESPONSE}}$ )

### Adjustable Bandwidth

The sensor dynamic can be adjusted with an external capacitor ( $C_F$ ). In this scenario, the bandwidth ( $f_{\text{BW}}$ ) can be calculated with Equation (7):

$$f_{\text{BW}} = \frac{1}{2\pi} \times \frac{1}{R_{\text{Fi}}(C_{\text{Fi}} + C_F)} \quad (7)$$

Where  $R_{\text{Fi}}$  is the internal filter resistance,  $C_{\text{Fi}}$  is the internal filter capacitance.

Figure 9 shows the typical bandwidth curve.

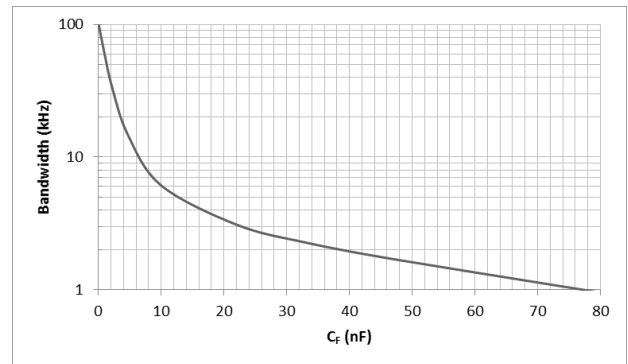


Figure 9: Bandwidth vs.  $C_F$

## APPLICATION INFORMATION

### Self-Heating Performance

The conductor and MCS1800 temperatures may rise when current flows through the primary conductor. Self-heating should be carefully verified to ensure that the IC’s junction temperature does not exceed the maximum value (165°C).

The thermal behavior depends significantly on the thermal environment of the IC, as well as its cooling capacity. In particular, thermal behavior depends on the PCB copper area’s thickness. The thermal response is also related to the current waveform’s profile (e.g. the amplitude and frequency of an AC current, or the peaks and duty cycle of a pulsed DC current).

Figure 10 shows the self-heating performance of the MCS1801 with a DC current input. The data is collected while the MCS1801 is mounted on the device’s evaluation board, and  $T_A = 25^\circ\text{C}$ . Values were taken 10 minutes after a continuous current.

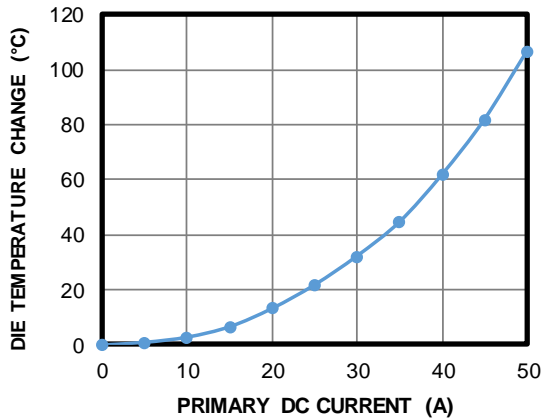
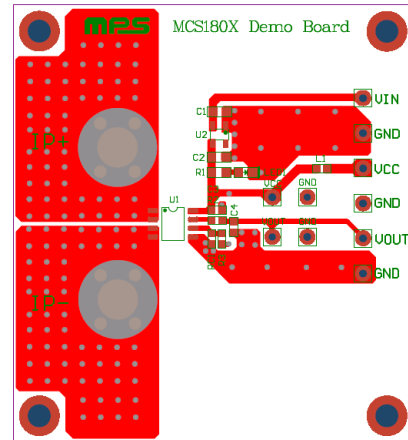
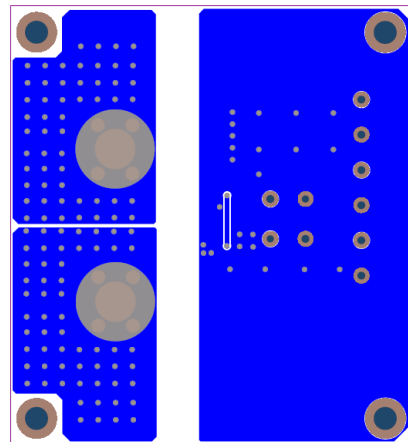


Figure 10: Self-Heating Performance with DC Current Input

Figure 11 shows the top and bottom layers of the PCB. The board includes a total of 2200mm<sup>2</sup>, 4oz (139μm) copper connected to the primary conductor via the IP+ and IP- pins. The copper covers both the top and bottom sides, and thermal vias connect the two layers.



Top Layer



Bottom Layer

Figure 11: Recommended PCB Layout

## TYPICAL APPLICATION CIRCUIT

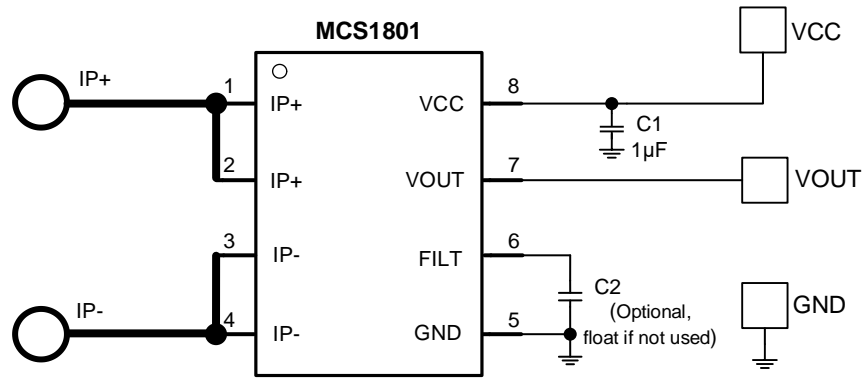
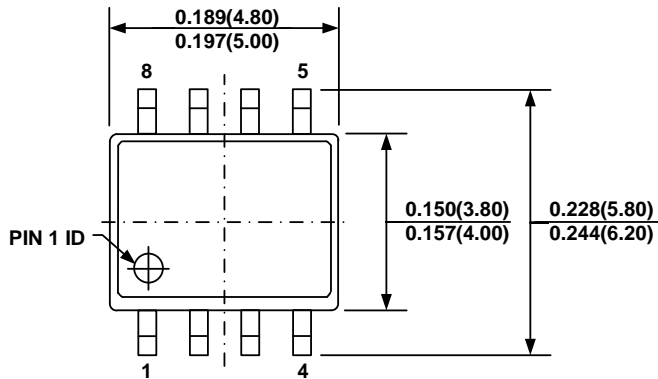


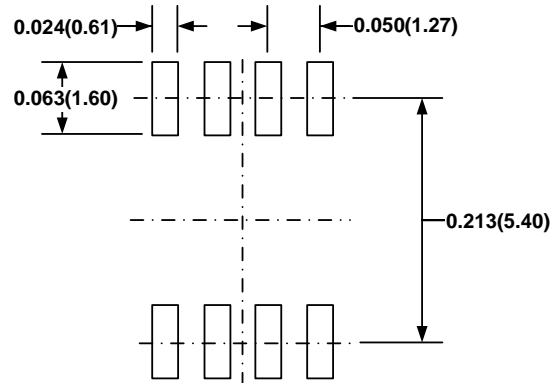
Figure 12: Typical Application Circuit

# PACKAGE INFORMATION

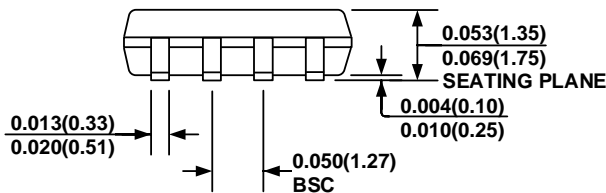
## SOIC-8



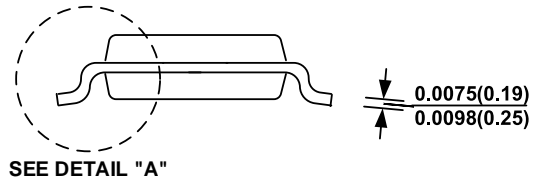
**TOP VIEW**



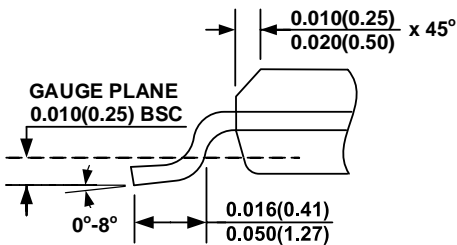
**RECOMMENDED LAND PATTERN**



**FRONT VIEW**



**SIDE VIEW**

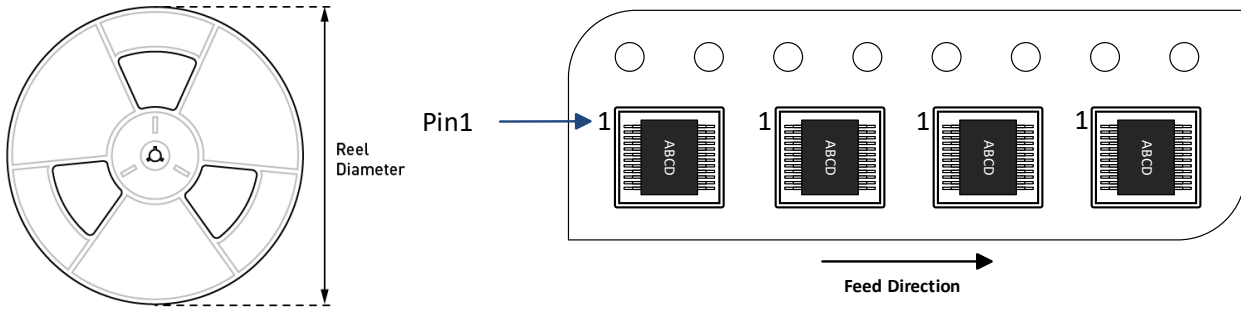


**DETAIL "A"**

**NOTE:**

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURR.
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- 6) DRAWING IS NOT TO SCALE.

### CARRIER INFORMATION



Part Number	Package Description	Quantity/ Reel	Quantity/ Tube	Quantity/ Tray	Reel Diameter	Carrier Tape Width	Carrier Tape Pitch
MCS1801GS-12-Z	SOIC-8	2500	N/A	N/A	13in	12mm	8mm
MCS1801GS-25-Z	SOIC-8	2500	N/A	N/A	13in	12mm	8mm



## REVISION HISTORY

Revision #	Revision Date	Description	Pages Updated
1.0	4/13/2021	Initial Release	-
1.1	8/19/2022	Added UL certification	1
		Updated “-Z” to “-Z” in the Ordering Information and Carrier Information sections	2, 16
		Added the Withstanding Current Capability table and Note 4	4
		Adjusted the note numbers for the EC table	5–6
		Updated Figure 3; updated the Noise ( $I_N$ ) section	10
		Updated the Power On Time ( $t_{PO}$ ), Propagation Delay ( $t_{PD}$ ), and Rising Time ( $t_R$ ) sections; updated Figures 5–7	11
		Updated Figure 8 and Figure 9	12
		Updated the Self-Heating Performance section; updated Figure 10 formatting	13

**Notice:** The information in this document is subject to change without notice. Please contact MPS for current specifications. Users should warrant and guarantee that third-party Intellectual Property rights are not infringed upon when integrating MPS products into any application. MPS will not assume any legal responsibility for any said applications.